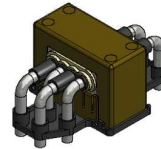


K-No.: 26543

1 A Differential Current Sensor for 5V Supply Voltage

For the electronic measurement of current: DC, AC, pulsed ..., with galvanic isolation between the primary and the secondary circuit



Date: 02.02.2017

Customer: Standard Type

Customers Part no:

Page 1 of 4

Description

- Closed loop (compensation) Current Sensor with magnetic probe
- Printed circuit board mounting
- Casing and materials UL-listed

Characteristics

- excellent accuracy
- very low offset current
- very low temperature dependency and offset drift
- very low hysteresis of offset current
- short response time
- wide frequency bandwidth
- compact design
- reduced offset ripple

Applications

Mainly used for stationary operation in industrial applications:

- Solar inverter

Electrical data - Ratings

I_{PN}	Primary nominal RMS current	85	A
$I_{\Delta N}$	Differential rated RMS current	1.0	A
V_{OUT}	Output voltage @ $I_{\Delta P}$	$V_{REF} \pm (1.2V * I_{\Delta P} / I_{\Delta N})$	V
$V_{OUT(0)}^1$	Output voltage @ $I_{\Delta P}=0A, \theta_A=25^\circ C$	$V_{REF} \pm 0.015$	V
$V_{OUT(Error)}$	in case of error (current sensor) $V_{OUT} < 0.5V$ is set	< 0.5	V
V_{REF}	internal reference voltage @ $I_{\Delta P}=0A$	2.5 ± 0.005	V
	external reference voltage range	1.4...3.5	V
$V_{REF(test\ current)}^2$	Reference voltage (external)	0 ... 0.1	V
$V_{OUT(test\ current)}^2$	Output voltage @ $V_{REF} = 0...0.1V$	$V_{OUT(0)} + 0.25 \pm 0.06$	V
K_N	Transformation ratio	1:1:1:1 : 20 : 1000	

¹ with switching on and after "test current" the sensor is degaussed by an internal AC-current for about 110ms.

In this time the output is set to $V_{OUT} < 0.5V$.

² If V_{REF} is set external to 0...0.1V an internal test current is generated.

Accuracy – Dynamic performance data

		min.	typ.	max.	Unit
$I_{\Delta P,max}$	Max. measuring range (differential current)	± 1.7			A
X	Accuracy @ $I_{PN}, \theta_A = 25^\circ C$			1.5	%
ϵ_L	Linearity			1	%
$V_O (V_{OUT}-V_{REF})$	Offset voltage @ $I_{\Delta P} = 0A, \theta_A = 25^\circ C$			15	mV
$\Delta V_O / \Delta T$	Temperature drift of V_{OUT} @ $I_{\Delta P}=0A, \theta_A$		0.05		mV/°C
t_r	Response time @ 90% of $I_{\Delta N}$		40		μs
f_{BW}	Frequency bandwidth	DC...8			kHz

General data

θ_A	Ambient operation temperature	-40		85	°C
θ_S	Ambient storage temperature (acc to M3101)	-40		85	°C
m	Mass		105		g
V_C	Supply voltage	4.75	5	5.25	V
I_C	Supply current at $I_{\Delta P} = 0A$ and RT		15		mA

^{1, 2} s_{clear} Clearance (component without solder pad) 3.9 mm

^{1, 2} s_{creep} Creepage (component without solder pad) 4.5 mm

¹ U_{sys} System Voltage *determines impulse voltage acc. table 7 600 V_{RMS}

¹ U_{AC} Working voltage *acc. table 10 800 V_{RMS}

¹ U_{PD} Rated discharge voltage *acc. table 24 with $U_{PD}=U_{AC}*\sqrt{2}$ 1132 V_{PEAK}

¹Constructed and manufactured and tested in accordance with IEC 61800-5-1:2007

Prim - Prim: Functional Insolation, Prim - Sec: Basic Insulation, Insulation material group 1, Pollution degree 2, Overvoltage category III

²According to customers specification

Date	Name	Issue	Amendment
02.02.2017	DJ	82	Page A1, M-sheet M3101 added to the storage temperature line. CN-17-007

Hrg.: MC-PD
editor

Bearb.: DJ
designer

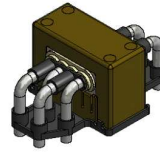
MC-PM: ZP
check

freig.: BEF
released

K-No.: 26543

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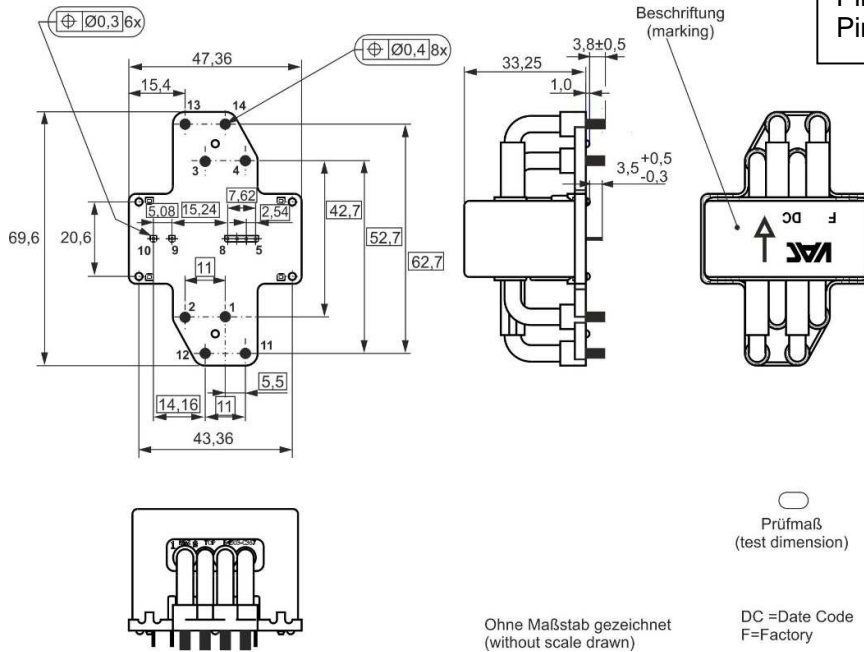
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Mechanical outline (mm):

General tolerances DIN ISO 2768-c

Connections:

Pin 5-10: 0.7mm x 0.7mm
Pin 1-4, 11-14: Ø4.5mm

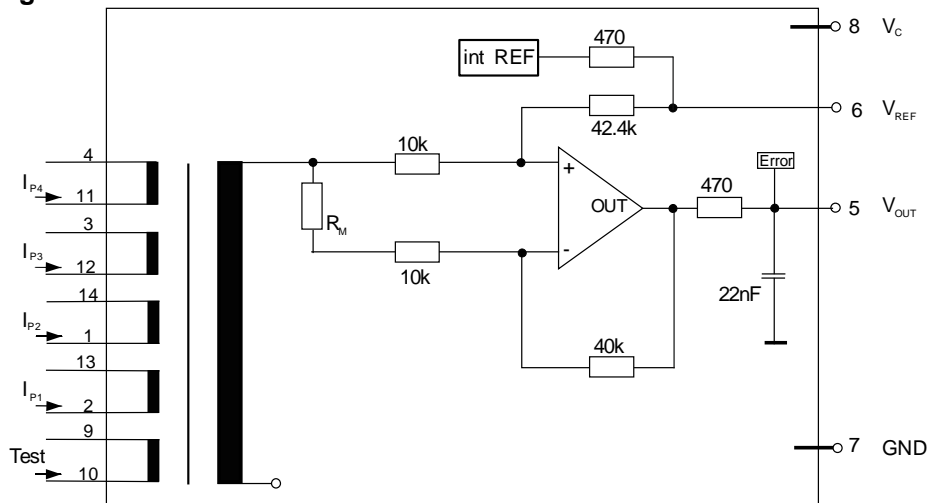


Marking:

VAC
4646-X931
F DC

Current direction: A positive output voltage appears at point V_{OUT} , if primary current flows in direction of the arrow.

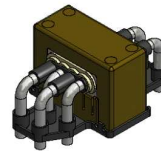
Schematic diagram:



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Electrical data: (investigate by a type checking)

		min.	typ.	max.	Unit
$V_{C,max}$	maximum supply voltage (without function)			6	V
I_C	Supply current with primary current	16mA+ $I_{\Delta P} \cdot K_N + V_{OUT}/R_L$			mA
$I_{OUT,SC}$	Short circuit output current		± 20		mA
R_S	Secondary coil resistance @ $\theta_A = 85^\circ C$			80	Ω
R_{Test}	Test winding resistance @ $\theta_A = 25^\circ C$		0.9		Ω
$R_{P1,P2}$	Primary wire resistance @ $\theta_A = 25^\circ C$		0.1		m Ω
$R_{i,REF}$	Internal resistance of reference input		470		Ω
$R_{i,OUT}$	Output resistance of V_{OUT}		470		Ω
$\Delta X_{Ti}/\Delta T$	Temperature drift of X @ $\vartheta_A = -40^\circ C \dots 85^\circ C$			400	ppm/K
$\Delta V_{REF}/\Delta T$	Temperature drift of V_{REF} @ $\vartheta_A = -40^\circ C \dots 85^\circ C$		5	50	ppm/K
$\Delta V_{O=}$ $\Delta(V_{OUT}-V_{REF})$	Sum of any offset drift including:		30		mV
V_{Ot}	Long term drift of V_O		10		mV
V_{OT}	Temperature drift of V_O @ $\vartheta_A = -40^\circ C \dots 85^\circ C$		10		mV
$\Delta V_O/\Delta V_C$	Supply voltage rejection ratio		20		mV/V
V_{OH}	Hysteresis of V_{OUT} @ $I_{\Delta P} = 0$ (after an overload of 1000x $I_{\Delta N}$)		125	250	mV
$V_{OH, Demag}$	Hysteresis after Degaussing			40	mV
V_{OSS}	Offsetripple (without external filter)			150	mV
V_{OSS}	Offsetripple (with 20 kHz-Filter, first order)		25		mV
V_{OSS}	Offsetripple (with 1.6 kHz-Filter, first order)		10		mV
	Mechanical stress according to M3209/3 Settings: 10-2000Hz, 1min/Octave, 2 hours		2		g

Routine Tests: (Measurement after temperature balance of the samples at room temperature, SC=significant characteristic)

$V_{OUT} (SC)$	(100%) M3011/6:	Output voltage vs. reference	1182 ... 1218	mV
V_O	(100%) M3226:	Offset voltage ($V_{OUT}-V_{REF}$)	15	mV
U_d	(100%) M3014:	Test voltage, 1s, Pin 1-4 vs. Pin 5-10, *acc. table 21	2.0	kV _{RMS}
U_{PDE}	(AQL 1/S4)	Partial discharge voltage (extinction)	1.2	kV _{RMS}
$U_{PDE} * 1.875$	M3024:	*acc. table 24 Pin 1-4 vs. Pin 5-10	1.5	kV _{RMS}

Requalification Tests: (replicated every year, Precondition acc. to M3236)

\hat{U}_W	M3064	Impulse test (1.2 μ s/50 μ s wave form) Pin 1-4 vs. Pin 5-10	6	kV
$\hat{U}_{W, prim-prim}$	M3064	Impulse test (1.2 μ s/50 μ s wave form) Pin 1 vs. Pin 11,12 and Pin 12 vs. Pin 1,2	6	kV
U_d	M3014	Test voltage, 5s Pin 1-4 vs. Pin 5-10	2.0	kV _{RMS}
$U_{d, prim-prim}$	M3014	Test voltage between primary conductors, 5s Pin 1 vs. Pin 11,12 and Pin 12 vs. Pin 1,2	2.0	kV _{RMS}
U_{PDE}	M3024	Partial discharge voltage (extinction)	1.2	kV _{RMS}
$U_{PDE} * 1.875$		*acc. table 24	1.5	kV _{RMS}

* IEC 61800-5-1:2007

Other instructions

- Temperature of the primary conductor should not exceed 100°C.
- Housing and bobbin material UL-listed: Flammability class 94V-0.

Hrg.: MC-PD
editor

Bearb.: DJ
designer

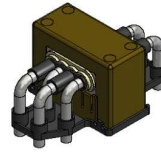
MC-PM: ZP
check

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Explanation of several terms used in the tables:

V_{Ot} Long term drift of V_O after 100 temperature cycles in the range -40°C to 85°C .

t_r Response time, measured as a delay time at $I_{\Delta P} = 0.9 \cdot I_{\Delta N}$ between a rectangular primary current and the output current or voltage.

t_{ra} Reaction time, measured as a delay time at $I_{\Delta P} = 0.1 \cdot I_{\Delta N}$ between a rectangular primary current and the output current or voltage.

$X_{ges}(I_{\Delta N})$ The sum of all possible errors over the temperature range by measuring a current $I_{\Delta N}$:

$$X_{ges}(I_{\Delta N}) = 100 \cdot \left| \frac{V_{OUT}(I_{\Delta N}) - 2.5V}{1.2V} - 1 \right| \%$$

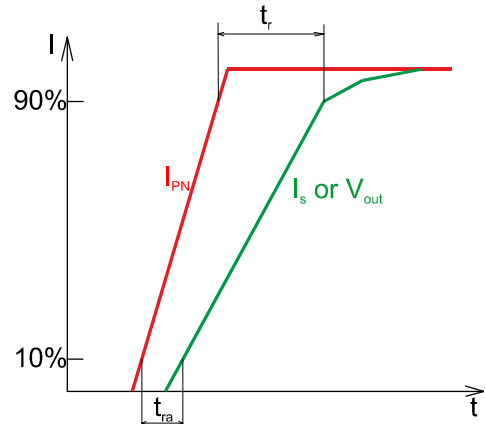
X Permissible measurement error in the final inspection at RT, defined by

$$X = 100 \cdot \left| \frac{V_{OUT}(I_{\Delta N}) - V_{OUT}(0)}{1.2V} - 1 \right| \%$$

ϵ_L Linearity fault defined by: $\epsilon_L = 100 \cdot \left| \frac{I_{\Delta P}}{I_{\Delta N}} - \frac{V_{OUT}(I_{\Delta P}) - V_{OUT}(0)}{V_{OUT}(I_{\Delta N}) - V_{OUT}(0)} \right| \%$

Where I_P is any input DC current and V_{OUT} the corresponding output term. ($I_0 = 0$).

RT Room temperature



Application Information

The external test current can be generated with the use of a resistor R and a switch X or something similar (Transistor, Mosfet, etc.). The resistor determine the current at a given voltage and so the output voltage can be calculated.

$$V_{OUT} = V_{REF} \pm \frac{1.2 \cdot \frac{5V}{R + R_{Test}} \cdot 20}{I_{\Delta N}}$$

